NSN 5962-01-250-6929

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:

794.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Programmed and schottky and bipolar and 3-state output and monolithic and w/enable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Current Rating Per Characteristic:

140.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

85.00 nanoseconds propagation delay time, high to low level output and 85.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Prom

Terminal Type And Quantity:

18 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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